NSN 5961-01-476-9766



Semiconductor Device Set - Page 1 of 1 View Online at https://aerobasegroup.com/nsn/5961-01-476-9766 **Overall Length:** Between 0.189 inches and 0.197 inches **Overall Height:** Between 0.049 inches and 0.059 inches Overall Width: Between 0.149 inches and 0.157 inches **Internal Configuration:** Field effect-dual gate all transistor **Channel Polarity And Control Type (non-core):** N-channel insulated gate type all transistor **Component Function Relationship:** Matched **Component Name And Quantity:** 2 transistor **Mounting Method:** Terminal all transistor **Voltage Rating In Volts Per Characteristic:** 60.0 drain to source voltage all transistor **Current Rating Per Characteristic:** 2.00 amperes zero-gate-voltage source current any acceptable all transistor **Power Rating Per Characteristic:** 2.4 watts small-signal input power, common-collector preset all transistor **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius junction all transistor **Terminal Type And Quantity:** 8 pin all transistor Shelf Life: N/a **Unit Of Measure: Demilitarization:** No

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